UNISONIC TECHNOLOGIES CO., LTD

US94060 Preliminary CMOS IC

HIGH SIDE POWER SWITCHES

■ DESCRIPTION

The UTC **US94060** are high-side load switches incorporating a low on-resistance P-channel MOSFET which provides customers over 2A continuous current.

The UTC **US94060** is characterized by a fast turn on function. The UTC **US94060** keeps in a floating state when an active pull-down signals is on the enable input until a high level signal applies on the EN pin. Built-in level shift circuitry allows low voltage logic signals to switch to higher supply voltages, on the contrary, high level logic signals can control low level voltages.

The UTC **US94060**'s operating voltage varies from 1.8V ~ 5.5 V which makes these devices suitable for 1-cell Lithium ion and 2- to 3-cell NiMH/NiCad/Alkaline powered systems as well as all 5V applications. The 2 μ A low operating current and low shutdown current(less than1 μ A) make the battery life longer.

The UTC **US94060** is generally suitable for applications, such as load switch in portable devices: cellular phones, PDAs, MP3 players, digital Cameras, portable instrumentation, battery switch-over circuits and level translators.



- * Operating voltage range: 1.8V ~ 5.5V
- * Providing 2A continuous operating current
- * P-channel MOSFET's R_{ON} : 175m Ω typical
- * Built-in level shift for control logic

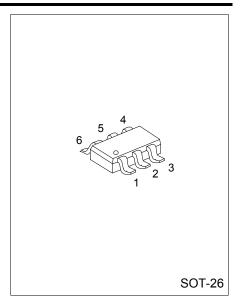
Ordering Number

- * Quiescent current is as low as 2µA
- * Micro-power shutdown less than 1µA

■ ORDERING INFORMATION

| US94060G-AG6-R | SOT- | 26 | Tape Reel |
|----------------|--|--|-----------|
| | 1)Packing Type 2)Package Type 3)Halogen Free | (1) R: Tape R (2) AG6: SOT (3) G: Haloge | -26 |

Package

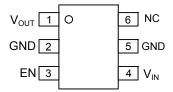


Packing

■ MARKING



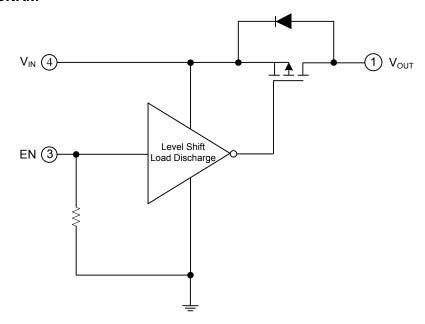
■ PIN CONFIGURATION



■ PIN DESCRIPTION

| PIN NO. | PIN NAME | DESCRIPTION |
|---------|------------------|--|
| 1 | V _{OUT} | Drain of P-channel MOSFET. |
| 2, 5 | GND | Ground connections. (Should both be connection to electrical ground). |
| 3 | EN | Enable (Input): Active-high CMOS compatible control input. Do not leave floating |
| 4 | V _{IN} | Source of P-channel MOSFET. |
| 6 | NC | No connect |

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATING

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|--|-----------------------|------------------|-------------|------|
| Input Voltage | | V _{IN} | +6 | V |
| Enable Voltage | | V _{EN} | +6 | V |
| Continuous Drain Current (Note 3) | T _A = 25°C | | ±2 | ^ |
| | T _A = 85°C | I _D | ±1.4 | A |
| Pulsed Drain Current (Note 5) | | I _{DP} | ±6 | Α |
| Continuous Diode Current (Note 7) | | Is | -50 | mA |
| Power Dissipation (Note 3)(T _A = 85°C) | | P _D | 270 | mW |
| Operating Ratings (Note 2) | | | | |
| Input Voltage Range | | V _{IN} | +1.8 ~ +5.5 | V |
| Junction Temperature | | TJ | +150 | °C |
| Storage Temperature (Note 4) | | T _{STG} | -55~+150 | °C |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

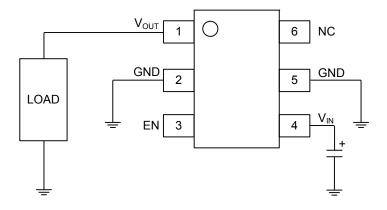
■ THERMAL DATA

| PARAMETER | SYMBOL | RATINGS | UNIT |
|------------------------------|---------------|---------|------|
| Junction to Ambient (Note 3) | θ_{JA} | 240 | °C/W |

■ **ELECTRICAL CHARACTERISTICS** (T_A = 25°C, unless otherwise specified.)

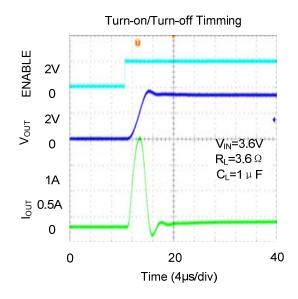
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|----------------------|--|-----|-----|------|------|
| Static | _ | | - | - | - | |
| EN Threshold Voltage | $V_{THD(EN))}$ | V_{IN} = 1.8V ~ 4.5V, I_D = -250 μ A | 0.5 | | 1.2 | V |
| EN Input Current (Quiescent Current) | $I_{Q(EN)}$ | $V_{IN} = V_{EN} = 5.5V$ | | 2 | 4 | μΑ |
| OFF State Leakage Current | I _{LEAK} | V _{EN} = OPEN or 0V, V _{IN} = +5.5V | | | 1 | μΑ |
| P-Channel Drain-Source On-Resistance | R _{DS(ON}) | V _{IN} = 4.5V, I _D = -100 mA, V _{EN} = 1.5V | | 175 | 200 | mΩ |
| | | V_{IN} = 3.6V, I_{D} = -100 mA, V_{EN} = 1.5V | | 185 | 215 | |
| | | V _{IN} = 2.5V, I _D = -100 mA, V _{EN} = 1.5V | | 205 | 245 | |
| | | V_{IN} = 1.8V, I_{D} = -100 mA, V_{EN} = 1.5V | | 270 | 325 | |
| Dynamic (Note 6) | | | | | | |
| Turn-ON Delay Time | $t_{D(ON)}$ | V_{IN} = 3.6V, I_{D} = -100mA, V_{EN} = 1.5V | | 850 | 1500 | ns |
| Turn-ON Rise Time | t_R | V _{IN} = 3.6V, I _D = -100mA, V _{EN} = 1.5V | 0.5 | 1 | 5 | μs |
| Turn-OFF Delay Time | t _{D(OFF)} | V_{IN} = 3.6V, I_{D} = -100mA, V_{EN} = 1.5V | | 100 | 150 | ns |
| Turn-OFF Fall Time | t_{F} | V_{IN} = 3.6V, I_{D} = -100mA, V_{EN} = 1.5V | | 60 | 100 | ns |

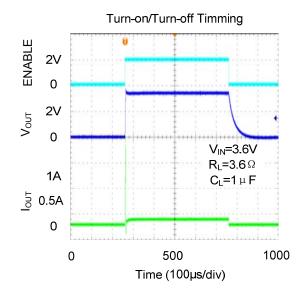
■ TYPICAL APPLICATION CIRCUIT

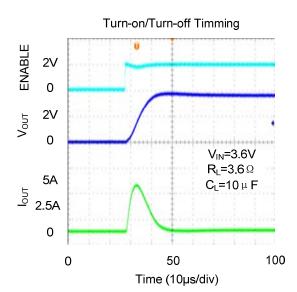


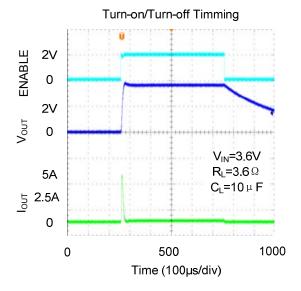
Load Switch Application with Capacitive Load Discharge

■ TYPICAL CHARACTERISTICS









UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.